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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

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January 2009

2SC5200/FJL4315 NPN Epitaxial Silicon Transistor

Applications

- · High-Fidelity Audio Output Amplifier
- · General Purpose Power Amplifier

Features

- High Current Capability: \(\begin{aligned}
 & = 17A. \end{aligned}
 \)
- · High Power Dissipation : 150watts.
- High Frequency: 30MHz.
- High Voltage : V_{EO}=250V
- · Wide S.O.A for reliable operation.
- · Excellent Gain Linearity for low THD.
- Complement to 2SA1943/FJL4215.
- · Thermal and electrical Spice models are available.
- · Same transistor is also available in:
 - -- TO3P package, 2SC5242/FJA4313: 130 watts
 - -- TO220 package, FJP5200: 80 watts
 - -- TO220F package, FJPF5200 : 50 watts



1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
BV _{CBO}	Collector-Base Voltage	250	V	
BV _{CEO}	Collector-Emitter Voltage	250	V	
BV _{EBO}	Emitter-Base Voltage	5	V	
I _C	Collector Current(DC)	17	А	
I _B	Base Current	1.5	А	
P _D	Total Device Dissipation(T _C =25°C) Derate above 25°C	150 1.04	W W/°C	
T _J , T _{STG}	Junction and Storage Temperature	- 50 ~ +1 50	°C	

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics* Ta=25°C unless otherwise noted

Symbol	Parameter	Max.	Units	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	0.83	°C/W	

^{*} Device mounted on minimum pad size

h_{FE} Classification

Classification	R	0	
h _{FE1}	55 ~ 110	80 ~ 160	

$\textbf{Electrical Characteristics*} \ \, \textbf{T}_{a} = 25 \, ^{\circ} \textbf{C unless otherwise noted}$

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =5mA, I _E =0	250			٧
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, R _{BE} =∞	250			٧
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =5mA, I _C =0	5			٧
I _{CBO}	Collector Cut-off Current	V _{CB} =230V, I _E =0			5.0	μА
I _{EBO}	Emitter Cut-off Current	V _{EB} =5V, I _C =0			5.0	μА
h _{FE1}	DC Current Gain	V _{CE} =5V, I _C =1A	55		160	
h _{FE2}	DC Current Gain	V _{CE} =5V, I _C =7A	35	60		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =8A, I _B =0.8A		0.4	3.0	٧
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =5V, I _C =7A		1.0	1.5	٧
f _T	Current Gain Bandwidth Product	V _{CE} =5V, I _C =1A		30		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, f=1MHz		200		pF

^{*} Pulse Test: Pulse Width=20µs, Duty Cycle≤2%

Ordering Information

Part Number	Marking	Package	Packing Method	Remarks
2SC5200RTU	C5200R	TO-264	TUBE	hFE1 R grade
2SC5200OTU	C5200O	TO-264	TUBE	hFE1 O grade
FJL4315RTU	J4315R	TO-264	TUBE	hFE1 R grade
FJL4315OTU	J4315O	TO-264	TUBE	hFE1 O grade

Typical Characteristics

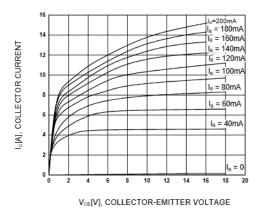


Figure 1. Static Characteristic

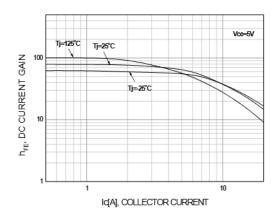


Figure 2. DC current Gain (R grade)

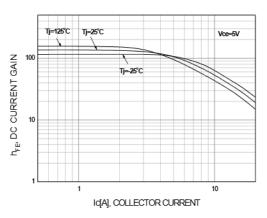


Figure 3. DC current Gain (O grade)

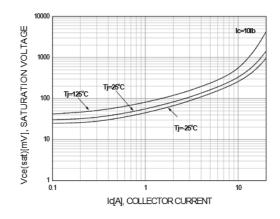


Figure 4. Collector-Emitter Saturation Voltage

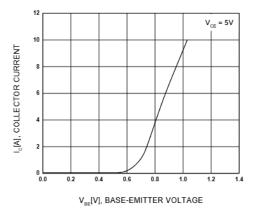


Figure 5. Base-Emitter On Voltage

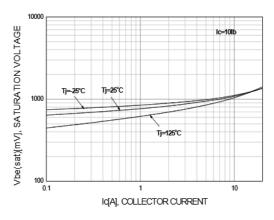


Figure 6. Base-Emitter Saturation Voltage

Typical Characteristics

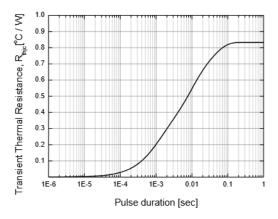


Figure 7. Power Derating

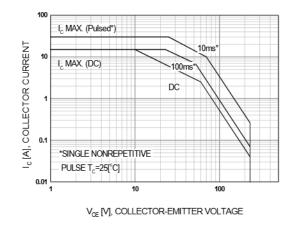


Figure 8. Safe Operating Area

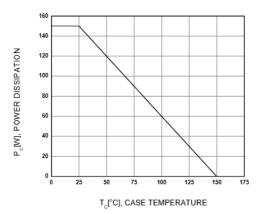
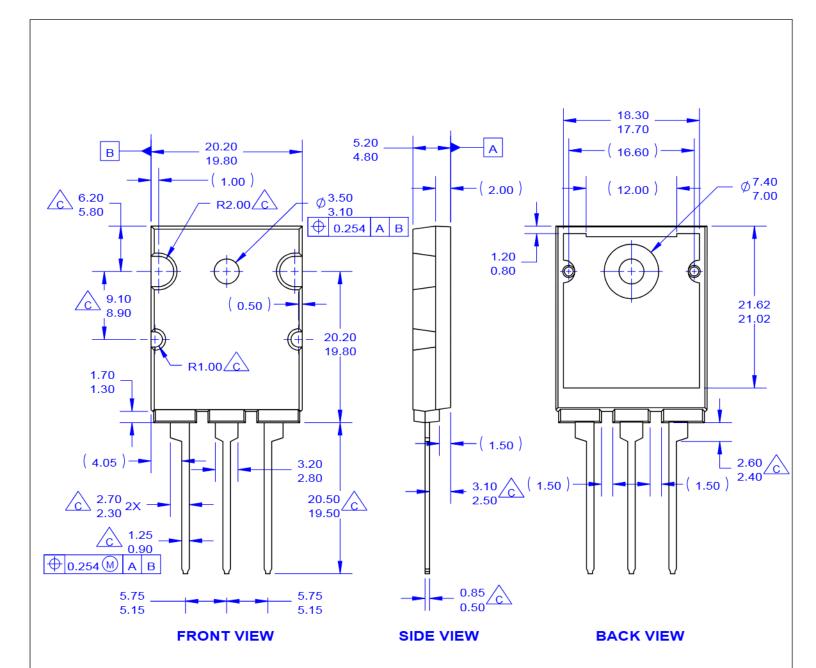
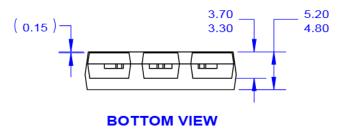


Figure 9. Power Derating







NOTES:

- A. PACKAGE REFERENCE: JEDEC TO264 VARIATION AA.
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- E. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- F. THIS PACKAGE IS INTENDED ONLY FOR "FS PKG CODE AR"
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